NSN 5962-01-266-8051

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-266-8051

Body Length:

Between 1.440 inches and 1.500 inches

Body Width:

Between 0.510 inches and 0.550 inches

Body Height:

Between 0.145 inches and 0.165 inches

Maximum Power Dissipation Rating:

525.0 milliwatts

Operating Tempurature Range:

-0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

Features Provided:

Electrostatic sensitive and ultraviolet erasable and w/enable and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

17 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

13.5 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0